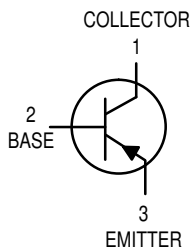
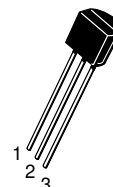


Low Noise Transistors

PNP Silicon



BC559, B, C
BC560C



CASE 29-04, STYLE 17
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	BC559	BC560	Unit
Collector–Emitter Voltage	V_{CEO}	–30	–45	Vdc
Collector–Base Voltage	V_{CBO}	–30	–50	Vdc
Emitter–Base Voltage	V_{EBO}	–5.0		Vdc
Collector Current — Continuous	I_C	–100		mA dc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625	5.0	mW mW/°C
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5	12	Watt mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = -10$ mA dc, $I_B = 0$)	BC559 BC560	$V_{(BR)CEO}$	–30 –45	— —	— —	Vdc
Collector–Base Breakdown Voltage ($I_C = -10$ μ A dc, $I_E = 0$)	BC559 BC560	$V_{(BR)CBO}$	–30 –50	— —	— —	Vdc
Emitter–Base Breakdown Voltage ($I_E = -10$ μ A dc, $I_C = 0$)		$V_{(BR)EBO}$	–5.0	—	—	Vdc
Collector Cutoff Current ($V_{CB} = -30$ Vdc, $I_E = 0$) ($V_{CB} = -30$ Vdc, $I_E = 0$, $T_A = +125^\circ\text{C}$)		I_{CBO}	— —	— —	–15 –5.0	nA dc μ A dc
Emitter Cutoff Current ($V_{EB} = -4.0$ Vdc, $I_C = 0$)		I_{EBO}	—	—	–15	nA dc



BC559, B, C BC560C**ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS					
DC Current Gain ($I_C = -10\ \mu\text{Adc}$, $V_{CE} = -5.0\ \text{Vdc}$) ($I_C = -2.0\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$)	h_{FE}	100 100 180 380 120	150 270 290 500 —	— — 460 800 800	—
Collector–Emitter Saturation Voltage ($I_C = -10\ \text{mAdc}$, $I_B = -0.5\ \text{mAdc}$) ($I_C = -10\ \text{mAdc}$, $I_B = \text{see note 1}$) ($I_C = -100\ \text{mAdc}$, $I_B = -5.0\ \text{mAdc}$, see note 2)	$V_{CE(\text{sat})}$	— — —	–0.075 –0.3 –0.25	–0.25 –0.6 —	Vdc
Base–Emitter Saturation Voltage ($I_C = -100\ \text{mAdc}$, $I_B = -5.0\ \text{mAdc}$)	$V_{BE(\text{sat})}$	—	–1.1	—	Vdc
Base–Emitter On Voltage ($I_C = -10\ \mu\text{Adc}$, $V_{CE} = -5.0\ \text{Vdc}$) ($I_C = -100\ \mu\text{Adc}$, $V_{CE} = -5.0\ \text{Vdc}$) ($I_C = -2.0\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$)	$V_{BE(\text{on})}$	— — –0.55	–0.52 –0.55 –0.62	— — –0.7	Vdc
SMALL–SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product ($I_C = -10\ \text{mAdc}$, $V_{CE} = -5.0\ \text{Vdc}$, $f = 100\ \text{MHz}$)	f_T	—	250	—	MHz
Collector–Base Capacitance ($V_{CB} = -10\ \text{Vdc}$, $I_E = 0$, $f = 1.0\ \text{MHz}$)	C_{cbo}	—	2.5	—	pF
Small–Signal Current Gain ($I_C = -2.0\ \text{mAdc}$, $V_{CE} = -5.0\ \text{V}$, $f = 1.0\ \text{kHz}$)	h_{fe}	240 450	330 600	500 900	—
Noise Figure ($I_C = -200\ \mu\text{Adc}$, $V_{CE} = -5.0\ \text{Vdc}$, $R_S = 2.0\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$) ($I_C = -200\ \mu\text{Adc}$, $V_{CE} = -5.0\ \text{Vdc}$, $R_S = 100\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$, $\Delta f = 200\ \text{kHz}$)	NF_1 NF_2	— —	0.5 —	2.0 10	dB

NOTES:

- I_B is value for which $I_C = -11\ \text{mA}$ at $V_{CE} = -1.0\ \text{V}$.
- Pulse test = $300\ \mu\text{s}$ – Duty cycle = 2%.

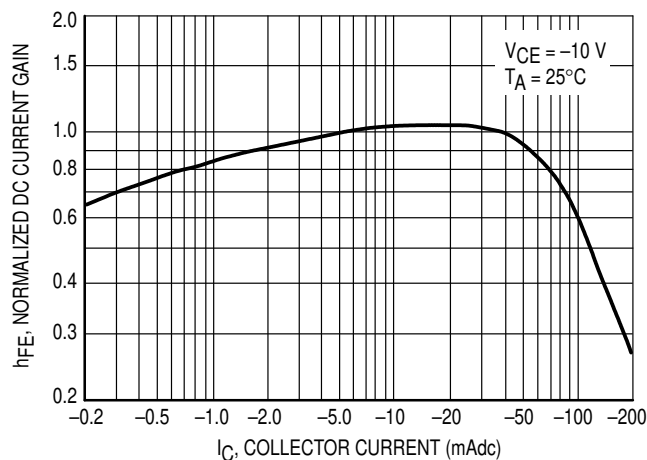


Figure 1. Normalized DC Current Gain

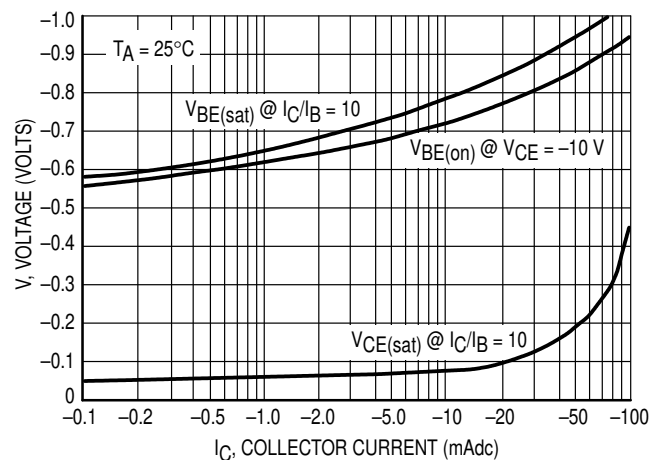


Figure 2. "Saturation" and "On" Voltages

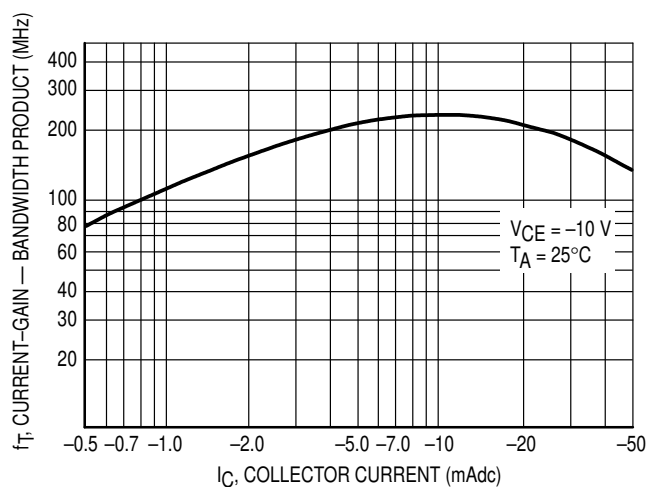


Figure 3. Current-Gain — Bandwidth Product

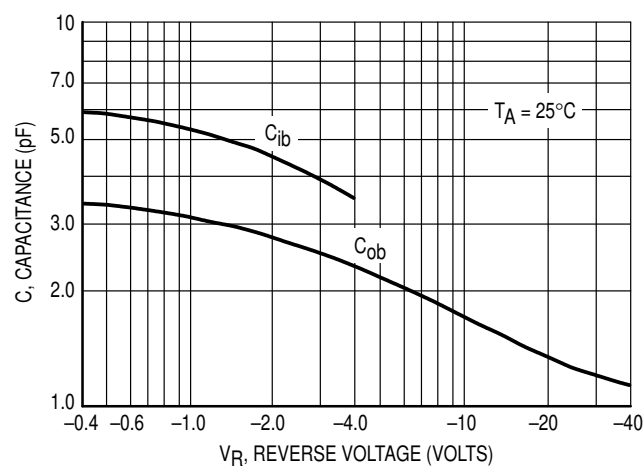


Figure 4. Capacitance

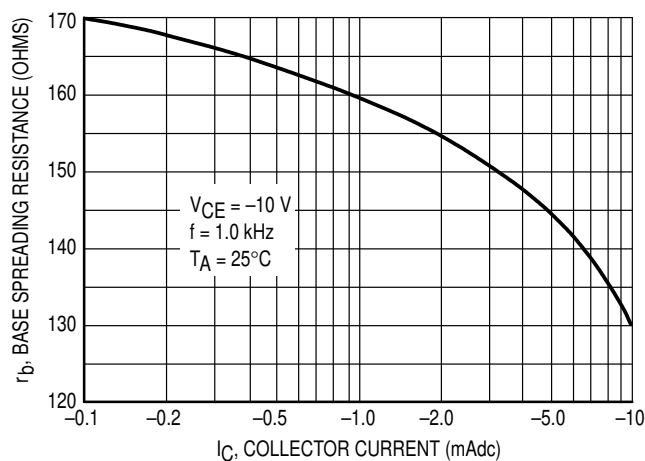
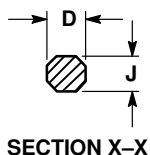
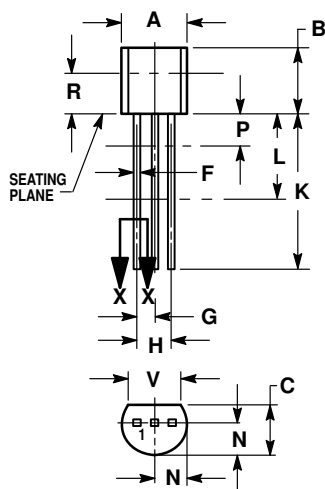


Figure 5. Base Spreading Resistance

PACKAGE DIMENSIONS



**CASE 029-04
(TO-226AA)
ISSUE AD**

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 17:

- PIN 1. COLLECTOR
- BASE
- EMITTER

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